NSN 5962-01-216-1142

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View Online at https://aerobasegroup.com/nsn/5962-01-216-1142

Body Length:

Between 1.235 inches and 1.265 inches

Body Width:

Between 0.540 inches and 0.560 inches

Body Height:

Between 0.135 inches and 0.160 inches

Operating Tempurature Range:

+0.0 to 70.0 degrees celsius

Storage Tempurature Range:

-65.0 to 150.0 degrees celsius

Features Provided:

Static operation and compatible dtl and 3-state output and bidirectional

Inclosure Material:

Plastic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

N-type metal oxide-semiconductor logic

Input Circuit Pattern:

14 input

Bit Quantity:

1024

Word Quantity:

128

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

450.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Test Data Document:

89536-586016 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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